



DGD2136M

3-PHASE HALF-BRIDGE GATE DRIVER IN SO-28

Description

The DGD2136M is a three-phase gate driver IC designed for highvoltage / high-speed applications, driving N-Channel MOSFETs and IGBTs in a half-bridge configuration. High-voltage processing techniques enable the DGD2136M's high-side to switch to 600V in a bootstrap operation.

The DGD2136M logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) for easy interfacing with controlling devices and are enabled low to better function in high noise environments. The driver outputs feature high-pulse current buffers designed for minimum driver cross conduction.

The DGD2136M offers numerous protection functions. A shootthrough protection logic prevents both outputs from being high when both inputs are high (fault state), an undervoltage lockout for VCC shuts down the respective high-side output. An overcurrent protection will terminate the six outputs. Both the VCC UVLO and the overcurrent protection trip an automatic fault clear with a timing that is adjustable with an external capacitor.

The DGD2136M is offered in SO-28 package and the operating temperature extends from -40°C to +125°C.

Applications

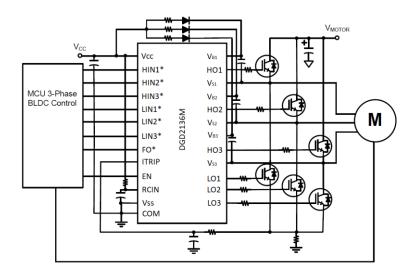
- 3-Phase Motor Inverter Driver
- White Goods Air Conditioner, Washing Machine, Refrigerator
- Industrial Motor Inverter Power Tools, Robotics
- General Purpose 3-Phase Inverter

Features

- Three Floating High-Side Drivers in Bootstrap Operation to 600V
- 200mA Source / 350mA Sink Output Current Capability
- Outputs Tolerant to Negative Transients, dV/dt Immune
- Logic Input 3.3V Capability
- Internal Deadtime of 290ns to Protect MOSFETs and IGBTs
- Matched Prop Delay for All Channels
- Outputs Out of Phase with Inputs
- Schmitt Triggered Logic Inputs
- Cross Conduction Prevention Logic
- Undervoltage Lockout for All Channels
- Overcurrent Protection Shuts Down Drivers
- Extended Temperature Range: -40°C to +125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: SO-28 (Type TH)
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (C3)
- Weight: 0.250 grams (Approximate)



Typical Configuration

SO-28

Top View

Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DGD2136MS28-13	DGD2136M	13	24	1,500

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

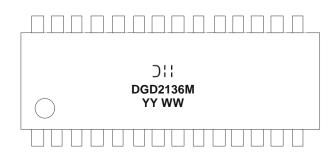
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

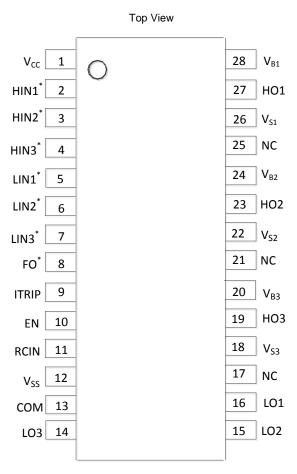


Marking Information



Diff = Manufacturer's Marking DGD2136M = Product Type Marking Code YY = Year (ex: 21 = 2021) WW = Week (01 to 53)

Pin Diagrams



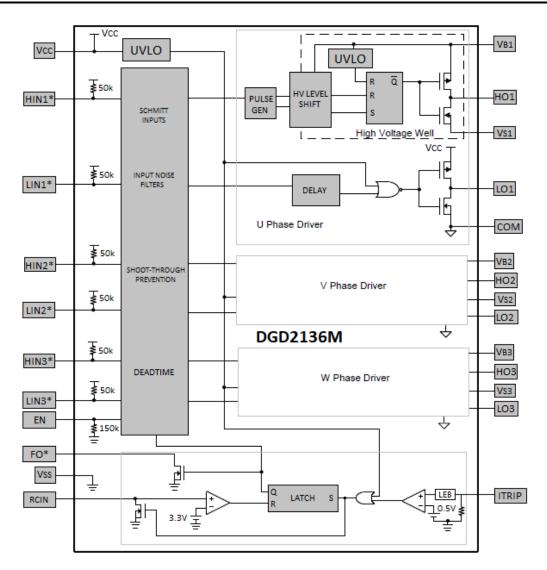
SO-28



Pin Descriptions

Pin Number	Pin Name	Function
1	Vcc	Low-Side and Logic Fixed Supply
2, 3, 4	HIN1*, HIN2*, HIN3*	Logic Input for High-Side Gate Driver Output, Out of Phase with HO
5, 6, 7	LIN1*, LIN2*, LIN3*	Logic Input for Low-Side Gate Driver Output, Out of Phase with LO
8	FO*	Fault Output with Open Drain (Fault with Overcurrent and V _{CC} UVLO)
9	ITRIP	Analog Input for Overcurrent Shutdown
10	EN	Logic Input for Functionality, I/O Logic Functions when EN is High
11	RCIN	An External RC Network Input used to Define FAULT CLEAR Delay
12	Vss	Logic Ground
13	COM	Low-Side Driver Return
14, 15, 16	LO3, LO2, LO1	Low-Side Gate Driver Output
17, 21, 25	NC	No Connection (No Internal Connection)
18, 22, 26	V _{S3} , V _{S2} , V _{S1}	High-Side Floating Supply Return
19, 23, 27	HO3, HO2, HO1	High-Side Gate Driver Output
20, 24, 28	Vb3, Vb2, Vb1	High-Side Floating Supply

Functional Block Diagram





Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
High-Side Floating Supply Voltage	VB	-0.3 to +624	V
High-Side Floating Supply Offset Voltage	Vs	V _B -24 to V _B +0.3	V
High-Side Floating Output Voltage	Vно	Vs-0.3 to V _B +0.3	V
Low-Side Output Voltage	Vlo	-0.3 to Vcc+0.3	V
Offset Supply Voltage Transient	dVs/dt	50	V/ns
Low-Side Fixed Supply Voltage	Vcc	-0.3 to +24	V
Logic Input Voltage (HIN*, LIN*, ITRIP, EN and FO*)	V _{IN}	-0.3 to +5.5	V

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor (Note 5)	PD	2.3	W
Thermal Resistance, Junction to Ambient (Note 5)	Reja	60	°C/W
Thermal Resistance, Junction to Case (Note 5)	Rejc	45	°C/W
Operating Temperature	TJ	+150	
Lead Temperature (Soldering, 10s)	TL	+300	°C
Storage Temperature Range	Tstg	-55 to +150	

Note: 5. When mounted on a standard JEDEC 2-layer FR-4 board.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
High-Side Floating Supply Absolute Voltage	VB	V _S + 10	V _S + 20	V
High-Side Floating Supply Offset Voltage	Vs	(Note 6)	600	V
High-Side Floating Output Voltage	Vно	Vs	VB	V
Low-Side Fixed Supply Voltage	Vcc	10	20	V
Low-Side Output Voltage	VLO	COM	Vcc	V
Logic Input Voltage (HIN*, LIN*, ITRIP & EN)	Vin	Vss	5	V
Fault Output Voltage	VFO	Vss	Vcc	V
Logic Ground	Vss	-5	5	V
Ambient Temperature	TA	-40	+125	°C

Note: 6. Logic operation for Vs of -5V to +600V.



DC Electrical Characteristics	6 (VBIAS (VCC, VBS) = 15V, @T _A = +25°C, unless otherwise specified.) (Note 7)
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Parameter	Symbol	Min	Тур	Max	Unit	Condition
Logic "0" Input Voltage	VIH	2.4	—	—	V	—
Logic "1" Input Voltage	VIL	—	_	0.8	V	_
High Level Output Voltage, V _{BIAS} - V _O	Voh	—	—	0.1	V	$I_O = 0 m A$
Low Level Output Voltage, Vo	Vol	—	_	0.1	V	$I_0 = 0 m A$
Offset Supply Leakage Current	Ilk		_	10	μA	$V_B = V_S = 600V$
Quiescent V _{BS} Supply Current	IBSQ	10	85	130	μA	$V_{IN} = 0V \text{ or } 5V, EN = 0V$
Quiescent Vcc Supply Current	lccq		1.1	1.6	mA	$V_{IN} = 0V \text{ or } 5V, EN = 0V$
Logic Input Bias Current (HO = LO = HIGH)	lin+	—	130	200	μA	$V_{IN} = 0V$
Logic Input Bias Current (HO = LO = LOW)	l _{IN-}	—	3.0	20	μA	$V_{IN} = 5V$
Logic Enable "1" Input Bias Current	I _{EN+}	—	33	80	μA	$V_{EN} = 5V$
Logic Enable "0" Input Bias Current	I _{EN-}	—	—	2.0	μA	$V_{EN} = 0V$
V _{BS} Supply Undervoltage Positive Going Threshold	VBSUV+	7.6	8.9	9.9	V	—
V _{BS} Supply Undervoltage Negative Going Threshold	VBSUV-	7.1	8.3	9.4	V	—
V _{CC} Supply Undervoltage Positive Going Threshold	V _{CCUV+}	7.6	8.9	9.9	V	—
Vcc Supply Undervoltage Negative Going Threshold	Vccuv-	7.1	8.3	9.4	V	_
Output High Short Circuit Pulsed Current	I _{O+}	120	200	—	mA	$V_0 = 0V$, PW $\leq 10\mu s$
Output Low Short Circuit Pulsed Current	lo-	250	350	-	mA	Vo = 15V, PW ≤ 10µs
Overcurrent Detect Positive Threshold	VITH+	400	500	600	mV	—
Overcurrent Detect Negative Threshold	VITH-	340	420	500	mV	—
Short-Circuit Input Current	Icsin	6.0	11	16	μA	Vcsin = 1V
RCIN Positive Going Threshold Voltage	VRCINTH+	7.0	8.4	9.8	V	—
RCIN Negative Going Threshold Voltage	VRCINTH-	—	5.0	_	V	—
Fault Output Low Level Voltage	VFOL	—	0.2	0.5	V	Vcs = 1V, IFO = 1.5mA
RCIN on Resistance	Rdsrcin	40	75	110	Ω	I _{RCIN} = 1.5mA
Fault Output on Resistance	Rdsfo	80	130	180	Ω	IFO = 1.5mA

Note: 7. The V_{IN}, V_{TH} and I_{IN} parameters are referenced to V_{SS} and are applicable to all six channels (HIN1*, 2*, 3* and LIN1*, 2*, 3*). The V_O and I_O parameters are applicable to the output pins (HO1, 2, 3 and LO1, 2, 3) and are referenced to COM.

AC Electrical Characteristics (VBIA	AS (VCC, VBS) = 15V, CL = 1000pF, @TA = +25°C, unless otherwise specifie	ed.)
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Parameter	Symbol	Min	Тур	Max	Unit	Condition
Turn-On Propagation Delay	ton	200	330	460	ns	Vs = 0V
Turn-Off Propagation Delay	tOFF	200	330	460	ns	$V_{S} = 0V$
Turn-On Rise Time	tr	—	90	150	ns	$V_S = 0V$
Turn-Off Fall Time	tf	—	35	60	ns	Vs = 0V
Delay Matching	t _{DM}	—	_	50	ns	—
Enable Low to Output Shutdown Delay	ten	225	330	425	ns	—
ITRIP Pin Leading-Edge Blanking Time	t BLT	200	300	400	ns	-
Time from ITRIP Triggering to FO*	t FLT	360	550	760	ns	From VITRIP = 1V to FO* turn off
Time from ITRIP Triggering to All Gate Outputs Turn Off	titrip	420	615	820	ns	From VITRIP = 1V to starting gate turn off
Input Filtering Time (HIN*, LIN*, EN)	t FLTIN	—	250	_	ns	—
Fault Clear Time	t FLTCLR	—	1.6	_	ms	$C_{RCIN} = 1nF,$ $R_{RCIN} = 2M\Omega$
Deadtime	t _{DT}	200	290	420	ns	—
Deadtime Matching	tdtm	—		50	ns	—
Output Pulse Width Matching (Note 8)	t _{PM}	—	50	75	ns	PW _{IN} > 1µs

Note: 8. t_{PM} is defined as $PW_{IN} - PW_{OUT}$.



Timing Waveforms

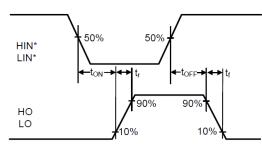
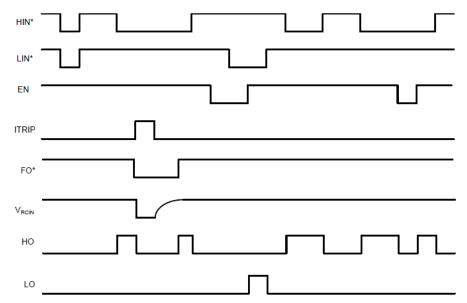


Figure 1. Switching Time Waveform Definitions





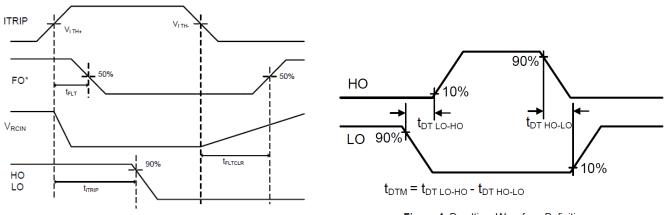


Figure 3. Overcurrent Timing Definitions



Typical Performance Characteristics (Vcc = 15V, @TA = +25°C, unless otherwise specified.)

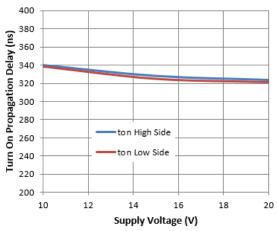


Figure 5. Turn-on Propagation Delay vs. Supply Voltage

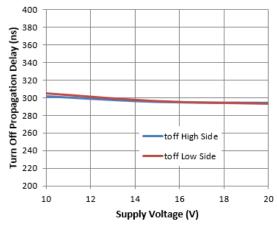


Figure 7. Turn-off Propagation Delay vs. Supply Voltage

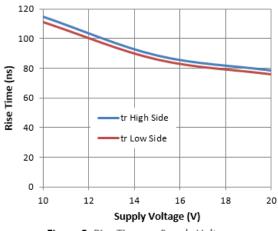


Figure 9. Rise Time vs. Supply Voltage

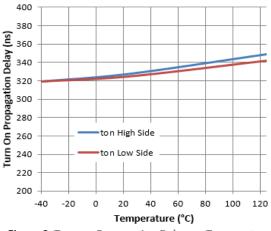
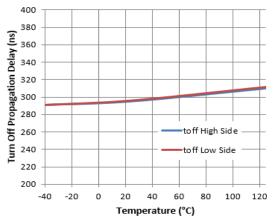
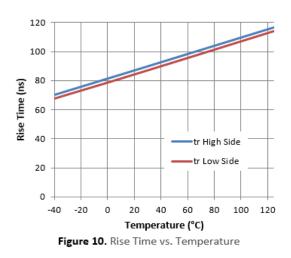


Figure 6. Turn-on Propagation Delay vs. Temperature









Typical Performance Characteristics (continued)

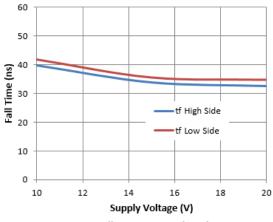


Figure 11. Fall Time vs. Supply Voltage

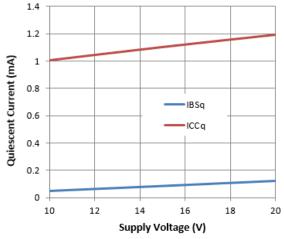
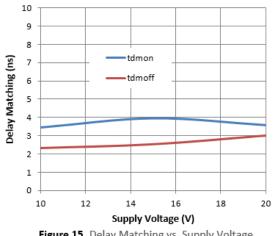


Figure 13. Quiescent Current vs. Supply Voltage





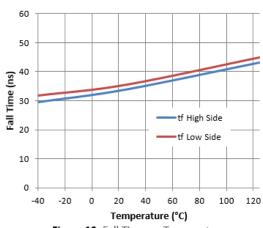
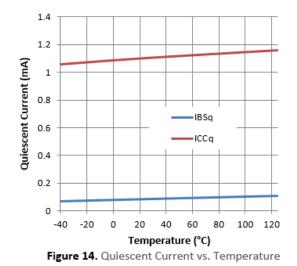


Figure 12. Fall Time vs. Temperature



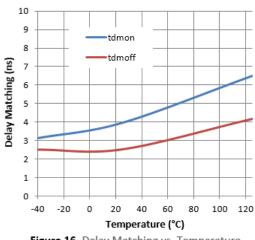


Figure 16. Delay Matching vs. Temperature



Typical Performance Characteristics (continued)

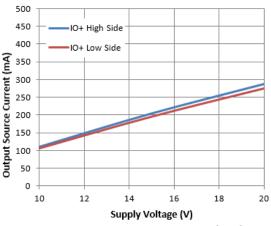


Figure 17. Output Source Current vs. Supply Voltage

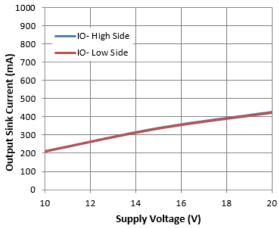


Figure 19. Output Sink Current vs. Supply Voltage

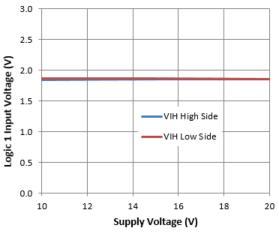


Figure 21. Logic 1 Input Voltage vs. Supply Voltage

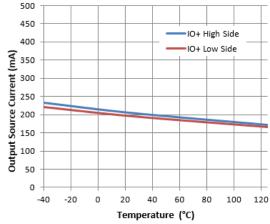
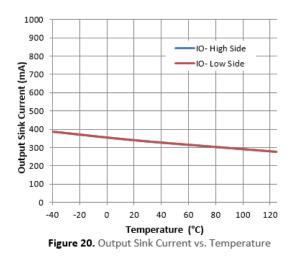


Figure 18. Output Source Current vs. Temperature



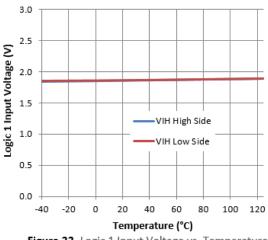


Figure 22. Logic 1 Input Voltage vs. Temperature



Typical Performance Characteristics (continued)

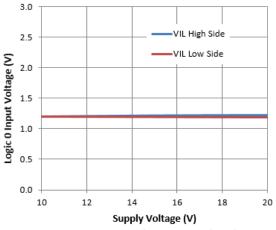


Figure 23. Logic 0 Input Voltage vs. Supply Voltage

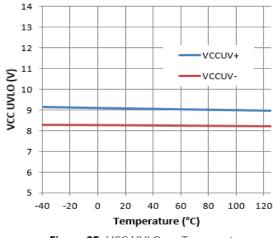
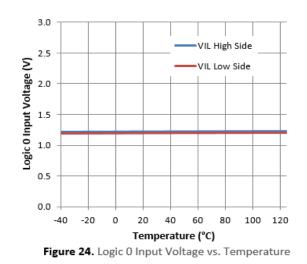


Figure 25. VCC UVLO vs. Temperature



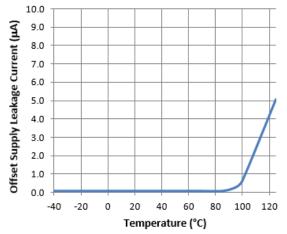


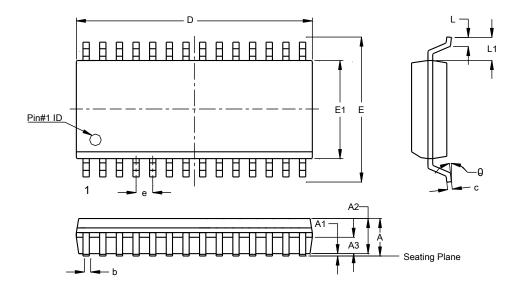
Figure 26. Offset Supply Leakage Current vs. Temperature



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

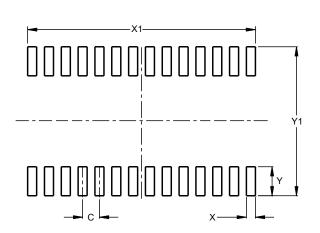
SO-28 (Type TH)



	SO-28 (Type TH)						
Dim	Min	Min Max Typ					
Α		2.65					
A1	0.10	0.30					
A2	2.25	2.35	2.30				
A3	0.97	1.07	1.02				
b	0.39	0.48					
С	0.25	0.31					
D	17.80	18.20	18.00				
E	10.10	10.50	10.30				
E1	7.30	7.70	7.50				
е		1.27 BSC	;				
L	0.70	1.00					
L1		1.40 BSC	;				
θ	0°	8°					
All	Dimens	ions in I	nm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.270
Х	0.680
X1	17.190
Y	2.200
Y1	11.300

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.

Document number: DS41225 Rev. 3 - 2

SO-28 (Type TH)



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 60249-1-CUT-TAPE
 0134220000
 6035
 60713816
 61161-90
 6131-204-23149P
 6131-205

 17149P
 6131-209-15149P
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 6131-220-21149P
 6131-260-2358P
 6131-265-11149P
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 6150-5001
 CSB4
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 621A
 622-4053LF
 6273
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 M55155/29XH06
 64-807
 65-1930-6
 CV500ISB02
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 CWD03-3
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 CX5032GB10000D0PPS02
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